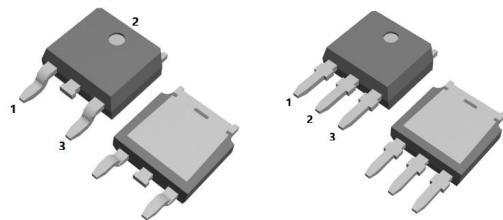
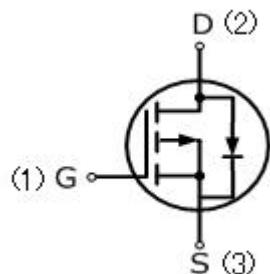


## 40P03(G,D)L

-40 Amps,-30 Volts P-CHANNEL MOSFET

### FEATURE

- -40A,-30V, $R_{DS(ON)MAX}=15\text{m}\Omega$  @ $V_{GS}=-10\text{V}/-15\text{A}$   
 $R_{DS(ON)MAX}=25\text{m}\Omega$  @ $V_{GS}=-4.5\text{V}/-15\text{A}$
- Low gate charge
- Low  $C_{iss}$
- Fast switching
- 100% avalanche tested
- Improved dv/dt capability
- RoHS 2.0 Compliant



TO-252-2L

40P03GL

TO-251-3L

40P03DL

### Absolute Maximum Ratings( $T_c=25^\circ\text{C}$ ,unless otherwise noted)

| Parameter  | Symbol         | 40P03(G,D)L | UNIT |
|--|----------------|-------------|------|
| Drain-Source Voltage   | $V_{DSS}$      | -30         | V    |
| Gate-Source Voltage  | $V_{GS}$       | $\pm 20$    |      |
| Continuous Drain Current   | $I_D$          | -40         | A    |
| Pulsed Drain Current(Note1)  | $I_{DM}$       | -120        |      |
| Single Pulse Avalanche Energy (Note 2)   | $E_{AS}$       | 151         | mJ   |
| Operating Junction and Storage Temperature Range                                 | $T_J, T_{STG}$ | -55 to +150 | °C   |
| Maximum lead temperature for soldering purposes,<br>1/8" from case for 5 seconds | $T_L$          | 260         | °C   |

### Thermal Characteristics

| Parameter                             | Symbol                 | 40P03(G,D)L | Units |
|---------------------------------------|------------------------|-------------|-------|
| Thermal resistance , Junction to Case | $R_{th(J-c)}$          | 2.8         | °C/W  |
| Maximum Power Dissipation             | $T_c=25^\circ\text{C}$ | $P_D$       | W     |

**Electrical Characteristics (T<sub>c</sub>=25°C,unless otherwise noted)**

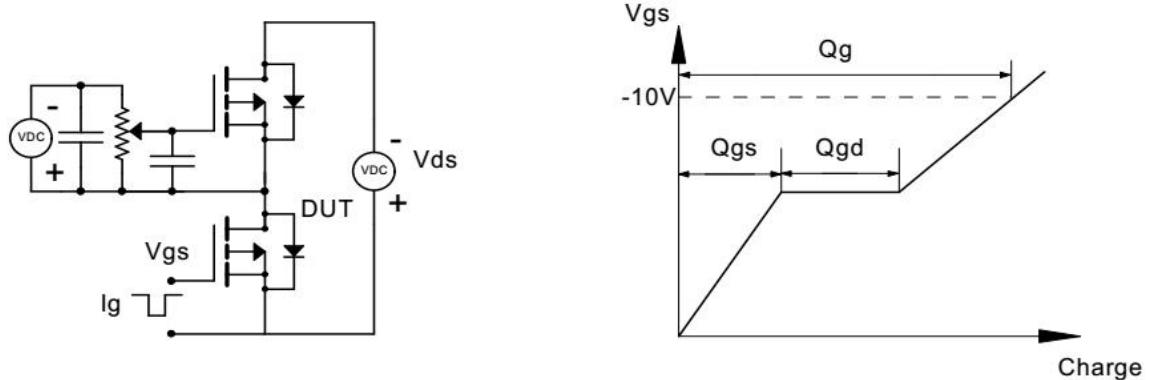
| Parameter  | Symbol              | Test Conditions  | Min  | Typ  | Max  | Units |
|--|---------------------|--|------|------|------|-------|
| <b>Off Characteristics</b>   |                     |  |      |      |      |       |
| Drain-Source Breakdown Voltage                                     | BV <sub>DSS</sub>   | V <sub>GS</sub> =0V,I <sub>D</sub> =-250uA   | -30  | —    | —    | V     |
| Zero Gate Voltage Drain Current                                    | I <sub>DSS</sub>    | V <sub>DS</sub> =-30V,V <sub>GS</sub> =0V  | —    | —    | -1   | uA    |
| Gate-Body Leakage Current,Forward                                  | I <sub>GSSF</sub>   | V <sub>GS</sub> =20V,V <sub>DS</sub> =0V   | —    | —    | 100  | nA    |
| Gate-Body Leakage Current,Reverse                                  | I <sub>GSSR</sub>   | V <sub>GS</sub> =-20V,V <sub>DS</sub> =0V  | —    | —    | -100 | nA    |
| <b>On Characteristics</b>  |                     |  |      |      |      |       |
| Gate-Source Threshold Voltage                                      | V <sub>GS(th)</sub> | V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =-250uA                                       | -1.2 | —    | -2.5 | V     |
| Drain-Source On-State Resistance                                   | R <sub>DS(on)</sub> | V <sub>GS</sub> =-10V,I <sub>D</sub> =-15A   | —    | 10   | 15   | mΩ    |
|  |                     | V <sub>GS</sub> =-4.5V,I <sub>D</sub> =-15A  | —    | 18   | 25   |       |
| <b>Dynamic Characteristics</b>                                     |                     |  |      |      |      |       |
| Input Capacitance  | C <sub>iss</sub>    | V <sub>DS</sub> =-15V,V <sub>GS</sub> =0V,<br>f=1.0MHZ   | —    | 2219 | —    | pF    |
| Output Capacitance   | C <sub>oss</sub>    |  | —    | 310  | —    | pF    |
| Reverse Transfer Capacitance                                       | C <sub>rss</sub>    |  | —    | 216  | —    | pF    |
| <b>Switching Characteristics</b>                                   |                     |  |      |      |      |       |
| Turn-On Delay Time   | t <sub>d(on)</sub>  | V <sub>DD</sub> =-15V,I <sub>D</sub> =-15A,<br>V <sub>GS</sub> =-10V,<br>R <sub>G</sub> =2.2 Ω | —    | 8.6  | —    | ns    |
| Turn-On Rise Time  | t <sub>r</sub>      |  | —    | 6.4  | —    | ns    |
| Turn-Off Delay Time  | t <sub>d(off)</sub> |  | —    | 46   | —    | ns    |
| Turn-Off Fall Time   | t <sub>f</sub>      |  | —    | 17   | —    | ns    |
| Total Gate Charge  | Q <sub>g</sub>      | V <sub>DS</sub> =-15V,V <sub>GS</sub> =-4.5V,<br>I <sub>D</sub> =-13.9A                        | —    | 45   | —    | nC    |
| Gate-Source Charge   | Q <sub>gs</sub>     |  | —    | 15   | —    | nC    |
| Gate-Drain Charge  | Q <sub>gd</sub>     |  | —    | 10   | —    | nC    |
| <b>Drain-Source Body Diode Characteristics and Maximum Ratings</b> |                     |  |      |      |      |       |
| Continuous Diode Forward Current                                   | I <sub>s</sub>      |  | —    | —    | -40  | A     |
| Pulsed Diode Forward Current                                       | I <sub>SM</sub>     |  | —    | —    | -120 | A     |
| Diode Forward Voltage  | V <sub>SD</sub>     | I <sub>s</sub> =-1A,V <sub>GS</sub> =0V  | —    | —    | -1.2 | V     |

**Notes**

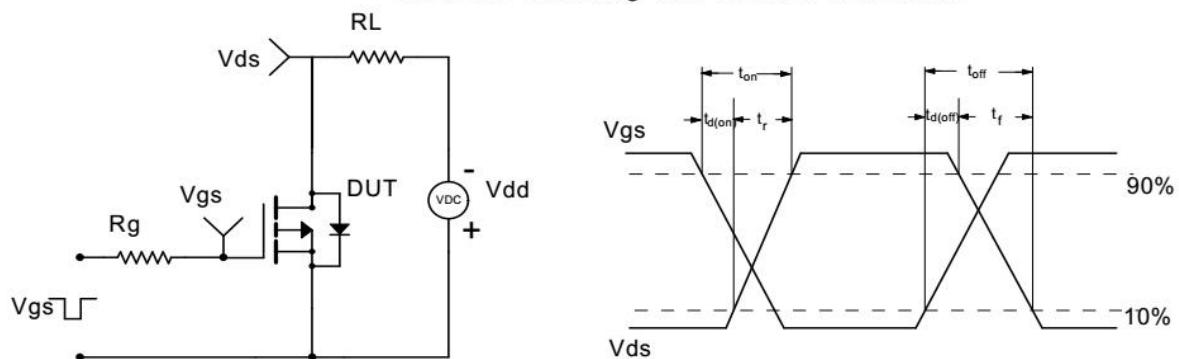
1. Repetitive Rating:pulse width limited by maximum junction temperature .
2. L=0.5mH,R<sub>g</sub>=25 Ω , T<sub>J</sub>=25°C.
3. Pulse width≤300us;duty cycle≤2%.

## Test Circuit and Waveform

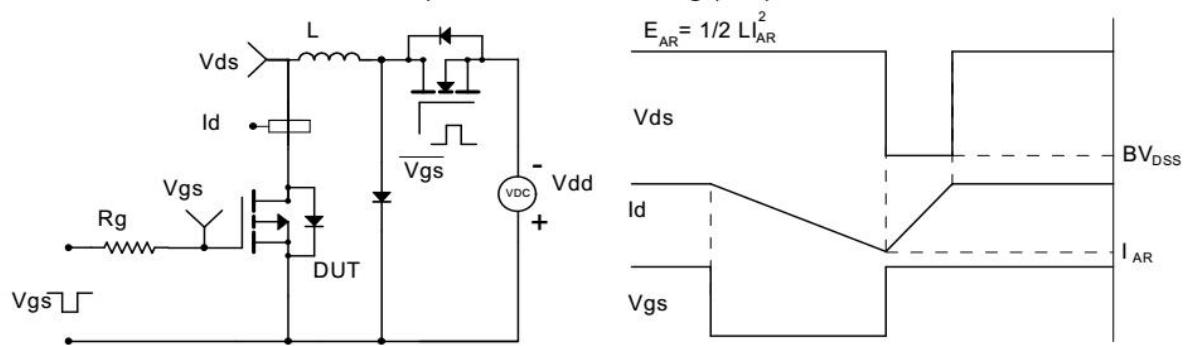
Gate Charge Test Circuit & Waveform



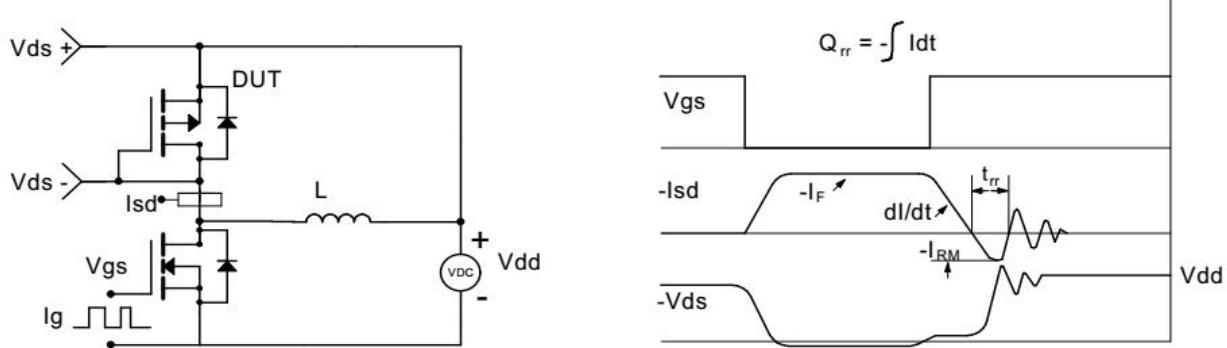
Resistive Switching Test Circuit & Waveforms

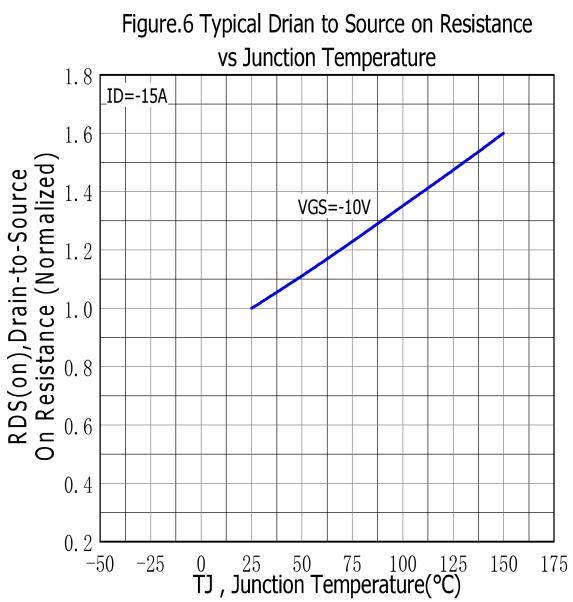
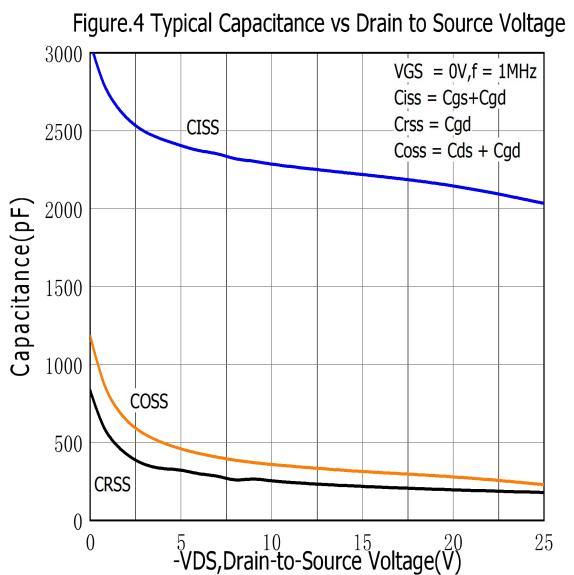
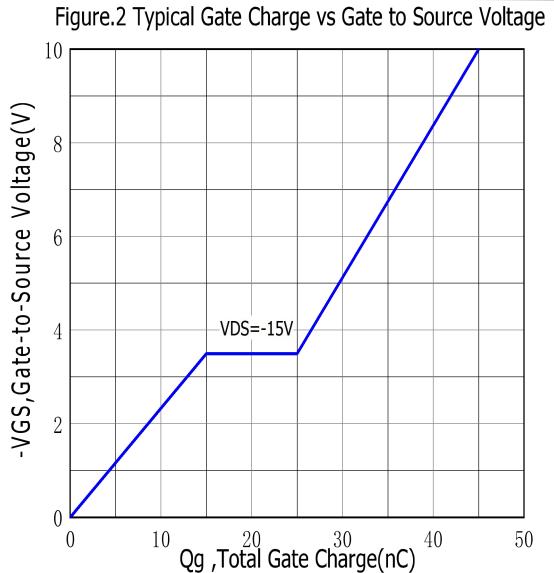
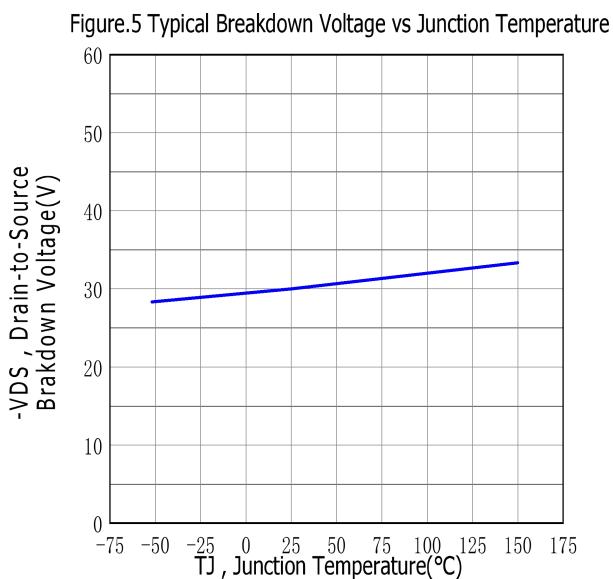
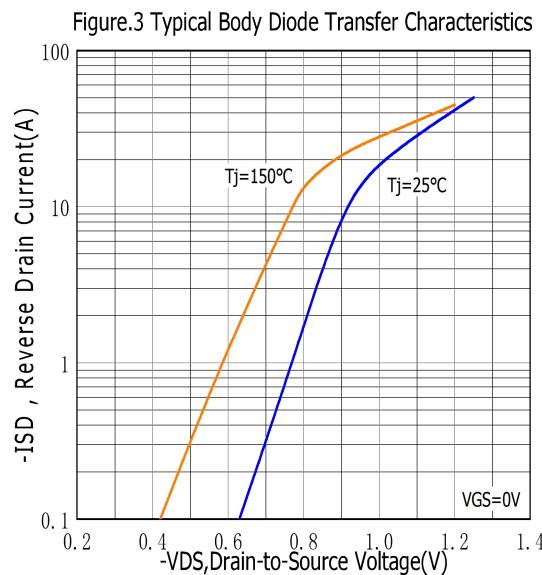
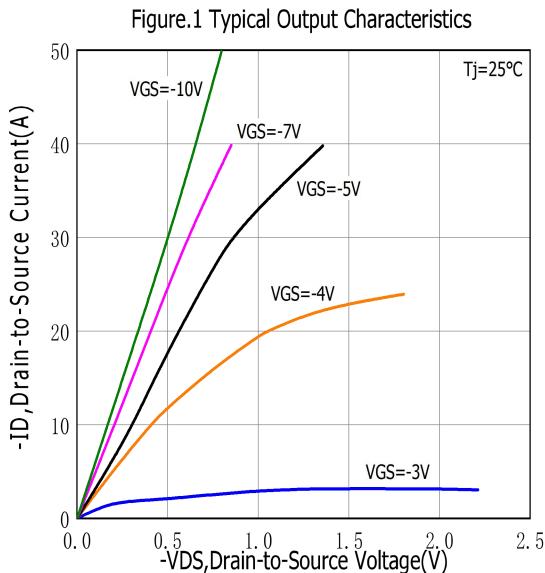


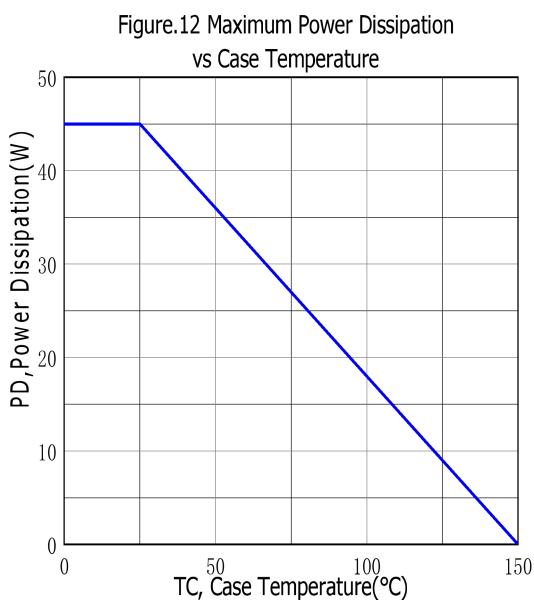
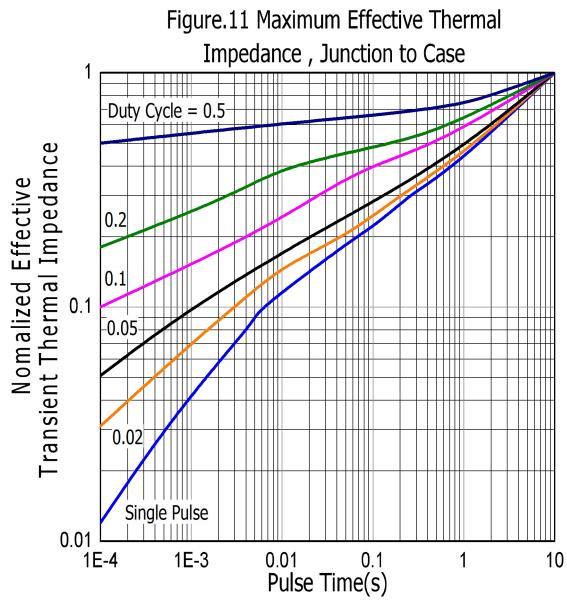
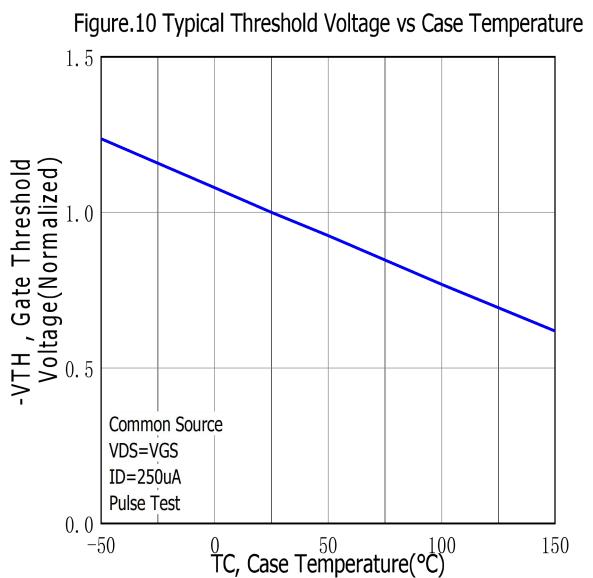
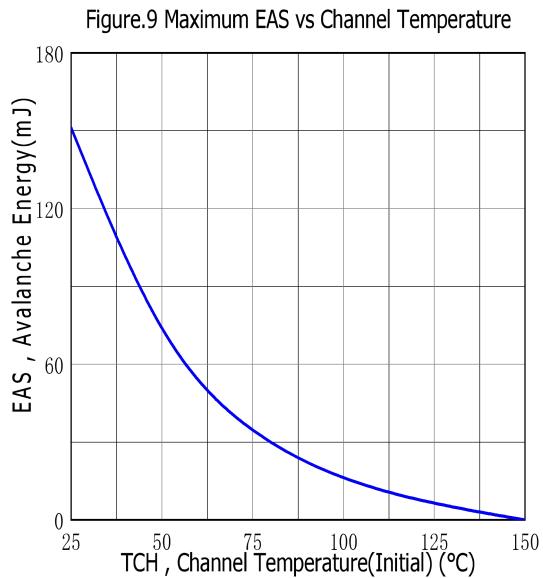
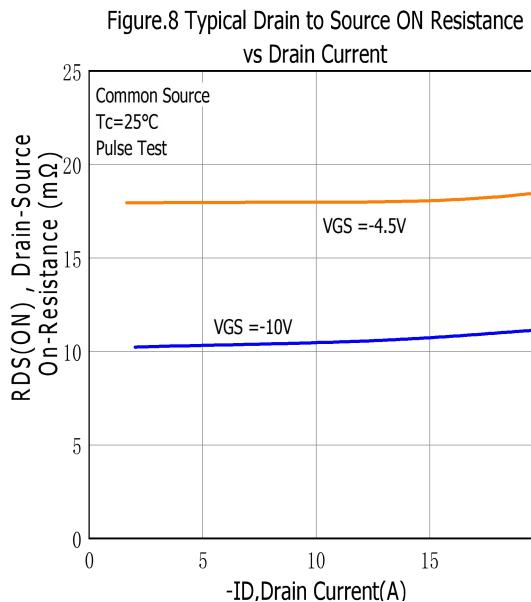
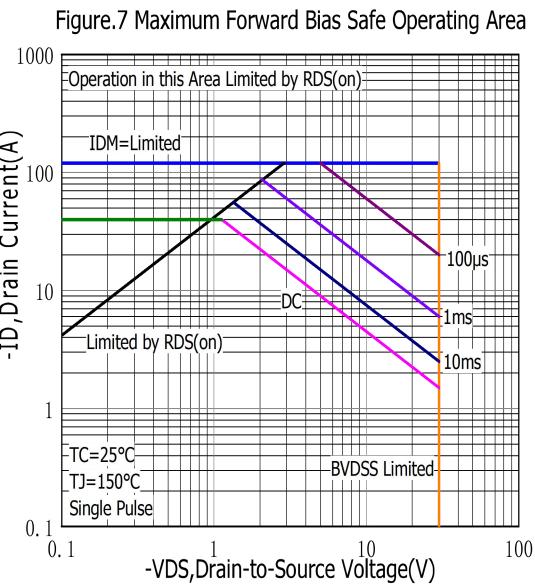
Unclamped Inductive Switching (UIS) Test Circuit & Waveforms



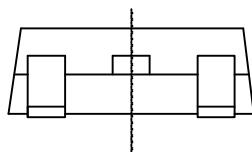
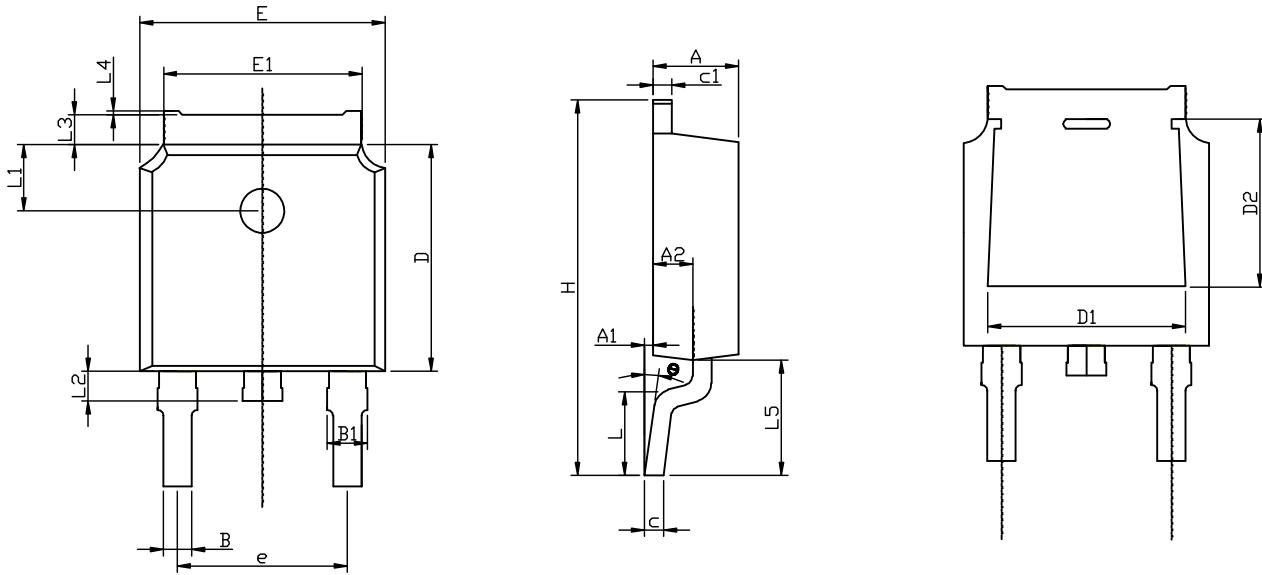
Diode Recovery Test Circuit & Waveforms



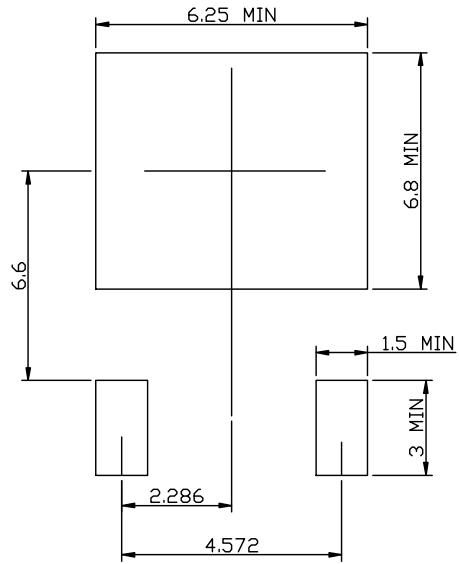




## TO-252-2L PACKAGE OUTLINE



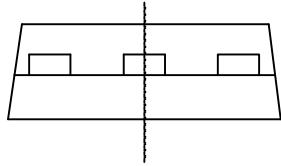
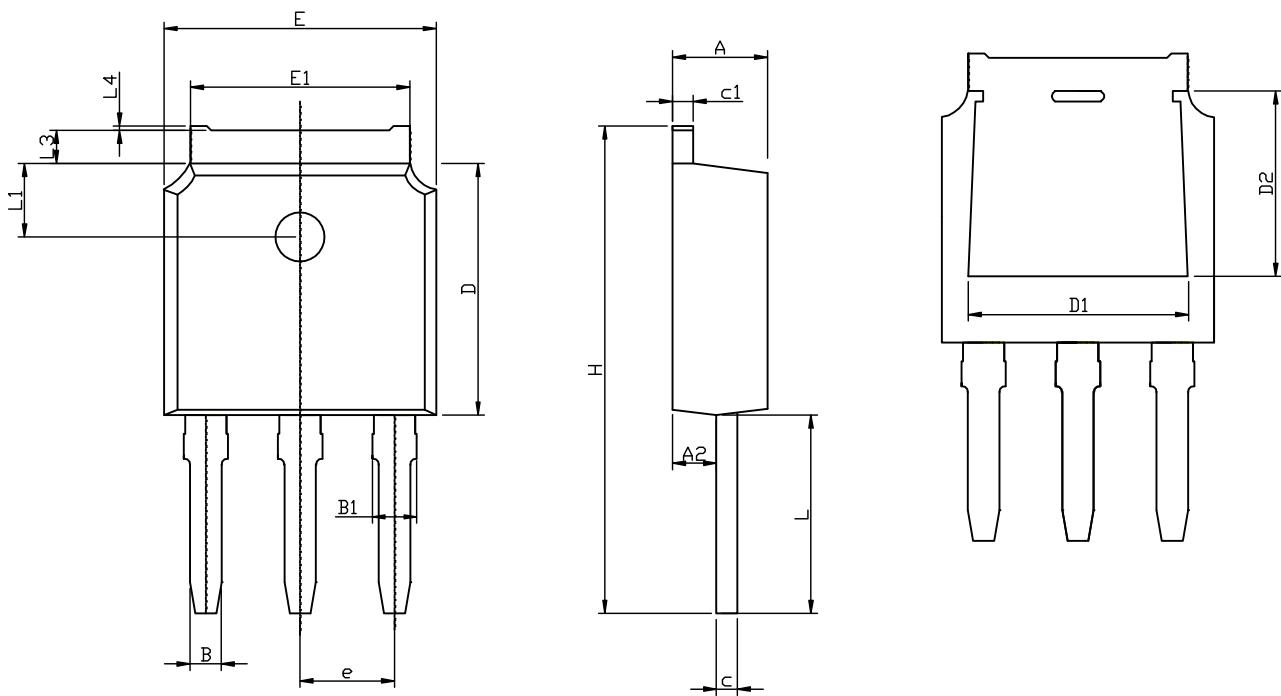
RECOMMENDED LAND PATTERN



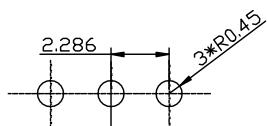
|    | MIN  | NOM      | MAX   |
|----|------|----------|-------|
| A  | 2.15 | 2.30     | 2.45  |
| A1 | 0.05 | 0.10     | 0.20  |
| A2 | 0.91 | 1.07     | 1.22  |
| B  | 0.66 | 0.76     | 0.86  |
| B1 | 0.93 | 1.08     | 1.23  |
| C  | 0.40 | 0.50     | 0.60  |
| C1 | 0.40 | 0.50     | 0.60  |
| D  | 5.95 | 6.10     | 6.25  |
| D1 | —    | 4.8REF   | —     |
| D2 | —    | 3.8REF   | —     |
| E  | 6.45 | 6.60     | 6.75  |
| E1 | 5.12 | 5.32     | 5.52  |
| L  |      | 1.65     |       |
| L1 | 1.58 | 1.78     | 1.98  |
| L2 | 0.60 | 0.80     | 1.00  |
| L3 | 0.70 | 0.85     | 1.00  |
| L4 | 0.00 | 0.05     | 0.20  |
| L5 | 2.80 | 3.10     | 3.40  |
| H  | 9.80 | 10.10    | 10.40 |
| Θ  | 0°   |          | 8°    |
| e  |      | 4.572REF |       |

UNIT: mm

## TO-251-3L PACKAGE OUTLINE



RECOMMENDED LAND PATTERN



UNIT: mm

|    | MIN   | NOM      | MAX   |
|----|-------|----------|-------|
| A  | 2.15  | 2.30     | 2.45  |
| A2 | 0.91  | 1.07     | 1.22  |
| B  | 0.66  | 0.76     | 0.86  |
| B1 | 0.93  | 1.08     | 1.23  |
| C  | 0.40  | 0.50     | 0.60  |
| C1 | 0.40  | 0.50     | 0.60  |
| D  | 5.95  | 6.10     | 6.25  |
| D1 | —     | 4.8REF   | —     |
| D2 | —     | 3.8REF   | —     |
| E  | 6.45  | 6.60     | 6.75  |
| E1 | 5.12  | 5.32     | 5.52  |
| L  | 4.50  | 4.80     | 5.10  |
| L1 | 1.58  | 1.78     | 1.98  |
| L3 | 0.70  | 0.85     | 1.00  |
| L4 | 0.00  | 0.05     | 0.20  |
| H  | 11.50 | 11.80    | 12.10 |
| e  |       | 2.286REF |       |